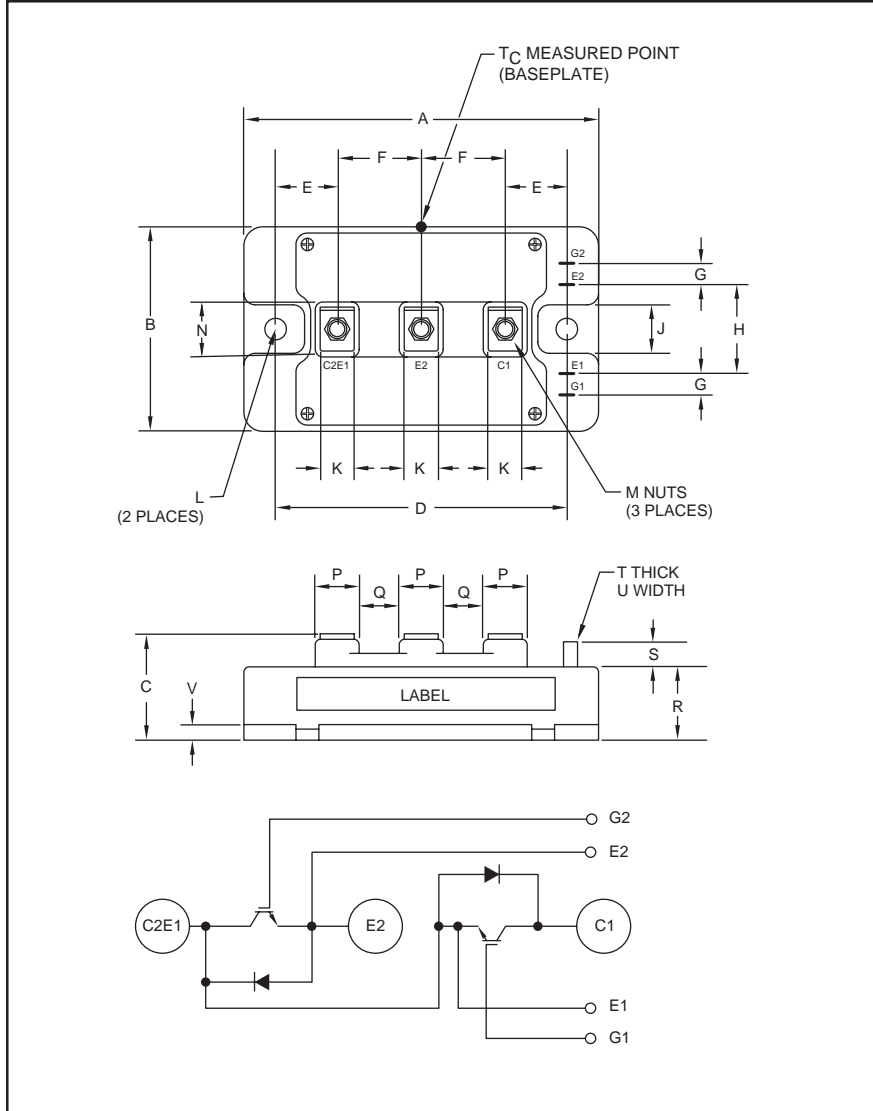


Dual IGBTMOD™ NF-Series Module 200 Amperes/600 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	3.70	94.0
B	1.89	48.0
C	1.14+0.04/-0.02	29.0+1.0/-0.5
D	3.15±0.01	80.0±0.25
E	0.67	17.0
F	0.91	23.0
G	0.16	4.0
H	0.71	18.0
J	0.51	13.0
K	0.47	12.0

Dimensions	Inches	Millimeters
L	0.26 Dia.	Dia. 6.5
M	M5 Metric	M5
N	0.79	20.0
P	0.63	16.0
Q	0.28	7.0
R	0.83	21.2
S	0.30	7.5
T	0.02	0.5
U	0.110	2.8
V	0.16	4.0



Description:

Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of two IGBT Transistors in a half-bridge configuration with each transistor having a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

Features:

- Low Drive Power
- Low $V_{CE(sat)}$
- Discrete Super-Fast Recovery Free-Wheel Diode
- Isolated Baseplate for Easy Heat Sinking

Applications:

- AC Motor Control
- UPS
- Battery Powered Supplies

Ordering Information:

Example: Select the complete part module number you desire from the table below -i.e. CM200DY-12NF is a 600V (V_{CES}), 200 Ampere Dual IGBTMOD™ Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 50)
CM	200	12



Powerex, Inc., 200 E. Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM200DY-12NF
Dual IGBTMOD™ NF-Series Module
 200 Amperes/600 Volts

Absolute Maximum Ratings, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	CM200DY-12NF	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Voltage (G-E Short)	V_{CES}	600	Volts
Gate-Emitter Voltage (C-E Short)	V_{GES}	± 20	Volts
Collector Current*** (DC, $T_C = 93^\circ\text{C}$)	I_C	200	Amperes
Peak Collector Current	I_{CM}	400*	Amperes
Emitter Current** ($T_C = 25^\circ\text{C}$)	I_E	200	Amperes
Peak Emitter Current**	I_{EM}	400*	Amperes
Maximum Collector Dissipation ($T_C = 25^\circ\text{C}$, $T_j \leq 150^\circ\text{C}$)	P_C	650	Watts
Mounting Torque, M5 Main Terminal	—	30	in-lb
Mounting Torque, M6 Mounting	—	40	in-lb
Weight	—	310	Grams
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	V_{ISO}	2500	Volts

*Pulse width and repetition rate should be such that device junction temperature (T_j) does not exceed T_{jMAX} rating.

Static Electrical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, $V_{GE} = 0V$	—	—	1.0	mA
Gate Leakage Current	I_{GES}	$V_{GE} = V_{GES}$, $V_{CE} = 0V$	—	—	0.5	μA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$I_C = 20\text{mA}$, $V_{CE} = 10V$	5.0	6.0	7.5	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 200\text{A}$, $V_{GE} = 15V$, $T_j = 25^\circ\text{C}$	—	1.7	2.2	Volts
		$I_C = 200\text{A}$, $V_{GE} = 15V$, $T_j = 125^\circ\text{C}$	—	1.7	—	Volts
Total Gate Charge	Q_G	$V_{CC} = 300V$, $I_C = 200\text{A}$, $V_{GE} = 15V$	—	800	—	nC
Emitter-Collector Voltage**	V_{EC}	$I_E = 200\text{A}$, $V_{GE} = 0V$	—	—	2.6	Volts

Dynamic Electrical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Input Capacitance	C_{ies}		—	—	30	nf
Output Capacitance	C_{oes}	$V_{CE} = 10V$, $V_{GE} = 0V$	—	—	3.7	nf
Reverse Transfer Capacitance	C_{res}		—	—	1.2	nf
Inductive	Turn-on Delay Time	$V_{CC} = 300V$, $I_C = 200\text{A}$,	—	—	120	ns
	Rise Time					
Load	Turn-off Delay Time	$V_{GE1} = V_{GE2} = 15V$, $R_G = 3.1\Omega$,	—	—	300	ns
	Fall Time					
Switch		Inductive Load	—	—	300	ns
Diode Reverse Recovery Time**	t_{rr}	Switching Operation,	—	—	150	ns
Diode Reverse Recovery Charge**	Q_{rr}	$I_E = 200\text{A}$	—	3.5	—	μC

*Pulse width and repetition rate should be such that device junction temperature (T_j) does not exceed $T_{j(max)}$ rating.

**Represents characteristics of the anti-parallel, emitter-to-collector free-wheel diode (FWDi)

*** T_c measured point is just under chips. If this value is used, $R_{th(f-a)}$ should be measured just under chips

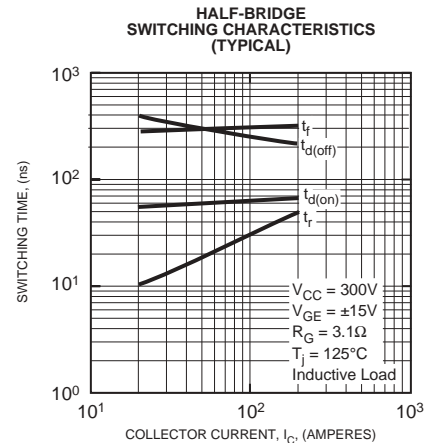
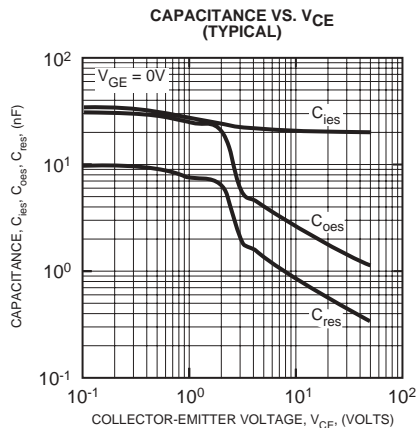
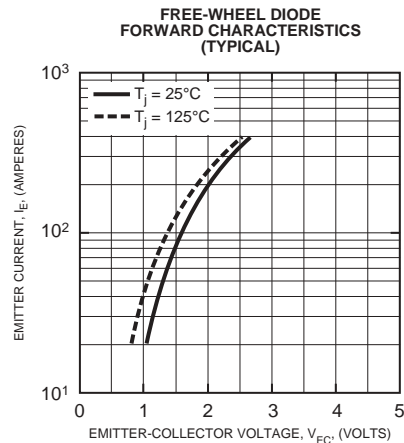
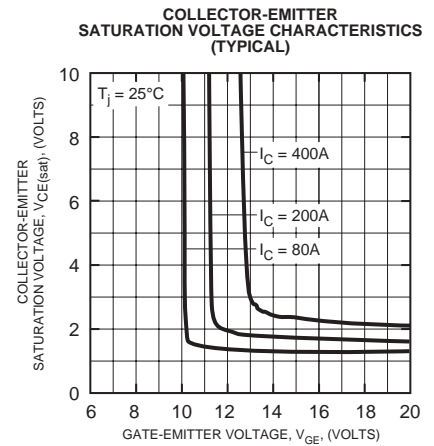
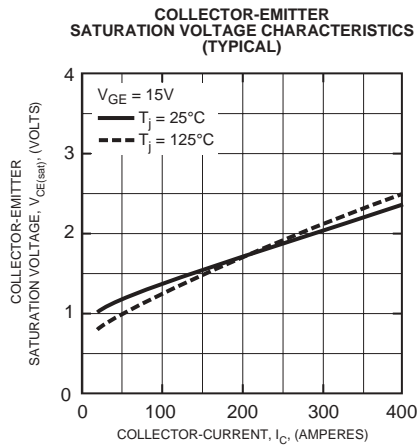
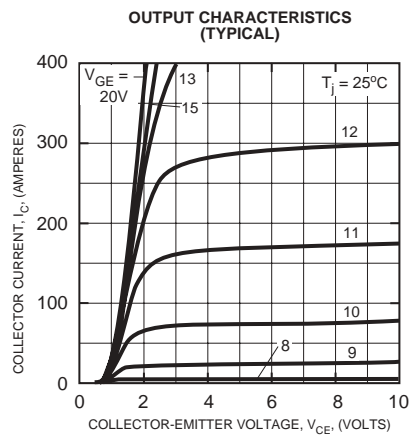


Powerex, Inc., 200 E. Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM200DY-12NF
Dual IGBTMOD™ NF-Series Module
 200 Amperes/600 Volts

Thermal and Mechanical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

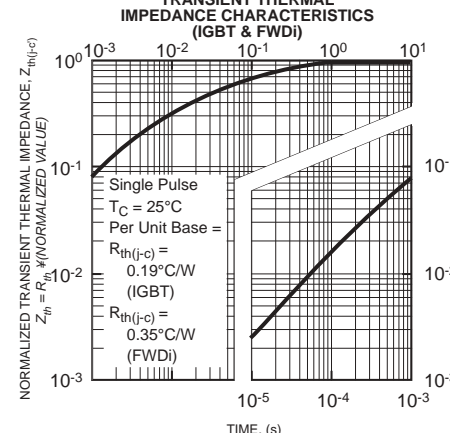
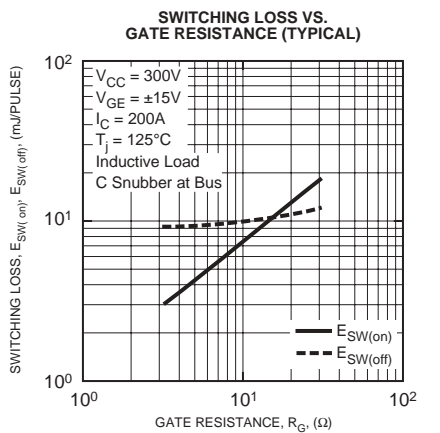
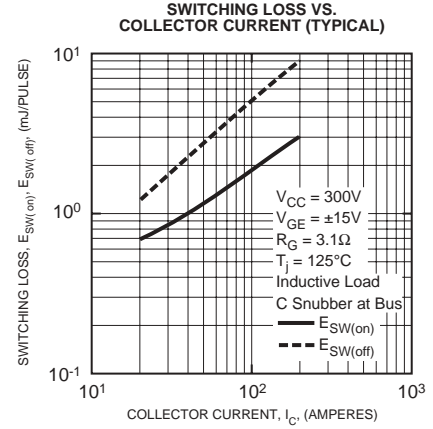
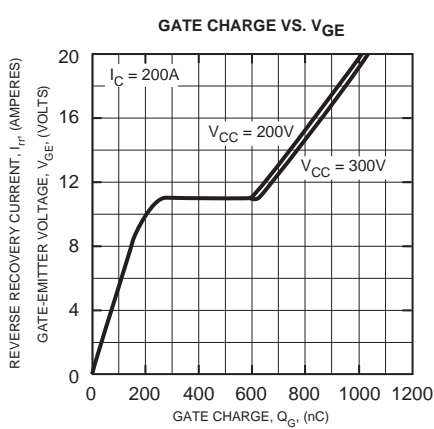
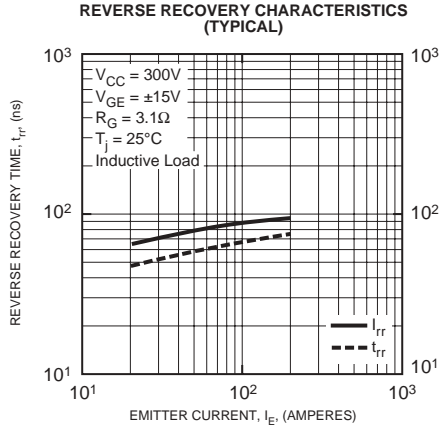
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{th(j-c)Q}$	Per IGBT 1/2 Module, T_C Reference Point per Outline Drawing	—	—	0.19	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{th(j-c)D}$	Per FWDi 1/2 Module, T_C Reference Point per Outline Drawing	—	—	0.35	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{th(j-c)Q}$	Per IGBT 1/2 Module, T_C Reference Point Under Chips	—	—	0.13	$^\circ\text{C/W}$
Contact Thermal Resistance	$R_{th(c-f)}$	Per 1/2 Module, Thermal Grease Applied	—	0.07	—	$^\circ\text{C/W}$
External Gate Resistance	R_G		3.1	—	31	Ω





Powerex, Inc., 200 E. Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM200DY-12NF
Dual IGBTMOD™ NF-Series Module
 200 Amperes/600 Volts



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [powerex manufacturer](#):

Other Similar products are found below :

[R7013003XXUA](#) [R9G01212XX](#) [VLA541-01R](#) [QRD0630T30](#) [CM400DY-24NF](#) [CM100TX-24S1](#) [CM600HA-24A](#) [NLD422PB](#)
[PSM03S93E5-A](#) [BP2B-V](#) [ND431625](#) [R5031213LSWS](#) [BG2B](#) [BG2C-5015](#) [ND431825](#) [T9G0121203DH](#) [CD611616C](#) [BG1A-PX](#)
[TCS4402802DH](#) [CD421690C](#) [PM600DVA060](#) [CD411899C](#) [CD631615B](#) [C601PB](#) [R5021213LSWS](#) [BG2A-NFH](#) [C180PB](#) [CD431690B](#)
[NLR425CM](#) [HARDWARE KIT 50](#) [CD410899C](#) [CM400HA-24A](#) [CD411699C](#) [LEAD KIT #NK](#) [HARDWARE KIT 49](#) [VLA500-01](#)
[HARDWARE KIT 87](#) [VLA106-24154](#) [VLA502-01](#) [VLA106-15242](#)